

Appl. No. 10/666,484
Amdt. dated October 21, 2004
Reply to Office Action dated July 21, 2004

Amendments to the Claims

Claims 1 – 39 (*Cancelled*)

40. (*Previously Presented*) A structure, comprising:

a light transmissive dielectric layer having a planar surface portion disposed above, and substantially vertically aligned with, an underlying reflective patterned conductive line, the light transmissive dielectric layer further having a non-planar portion, and a non-planar non-light-transmissive region disposed on the non-planar portion of the light transmissive dielectric layer.

41. (*Previously Presented*) The structure of Claim 40, wherein the non-light-transmissive region includes a non-planar anti-reflective layer embedded therein.

42. (*Previously Presented*) The structure of Claim 41, wherein the anti-reflective layer comprises a material selected from the group consisting of amorphous silicon and silicon oxynitride.

43. (*Previously Presented*) The structure of Claim 42, wherein the dielectric layer is disposed over a semiconductor wafer.